

74VHC14

Hex Schmitt Inverter

General Description

The 74VHC14 is an advanced high speed CMOS Hex Schmitt Inverter fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. Pin configuration and function are the same as the 74HC04 but the inputs have hysteresis between the positive-going and negative-going input thresholds, which are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals, thus providing greater noise margin than conventional inverters.

An input protection circuit ensures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

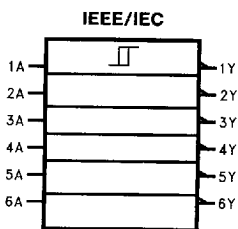
- Low power dissipation:
 $I_{CC} = 2 \mu A$ (Max) at $T_A = 25^\circ C$
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (Min)
- All inputs are equipped with a power down protection function
- Balanced propagation delays: $T_{PLH} \approx T_{PHL}$
- Low noise: $V_{OLP} = 0.8V$ (Max)
- Pin and function compatible with 74HC14

Ordering Code: See Section 6

Commercial	Package Number	Package Description
74VHC14M	M14A	14-Lead Molded JEDEC SOIC
74VHC14SJ	M14D	14-Lead Molded EIAJ SOIC
74VHC14MSC	MSC14	14-Lead Molded EIAJ Type 1 SSOP
74VHC14MTC	MTC14	14-Lead Molded JEDEC Type 1 TSSOP
74VHC14N	N14A	14-Lead Molded DIP

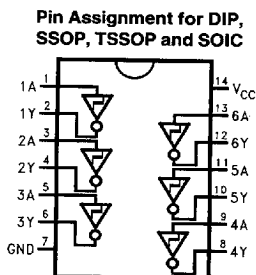
Note: Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code. EIAJ Type 1 SSOP available on Tape and Reel only, order MSCX.

Logic Symbol



TL/F/11617-1

Connection Diagram



TL/F/11617-2

Truth Table

A-Inputs	Y-Outputs
L	H
H	L

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	-0.5V to +7.0V
DC Input Voltage (V_{IN})	-0.5V to +7.0V
DC Output Voltage (V_{OUT})	-0.5V to $V_{CC} + 0.5V$
Input Diode Current (I_{IK})	-20 mA
Output Diode Current (I_{OK})	± 20 mA
DC Output Current (I_{OUT})	± 25 mA
DC V_{CC} /GND Current (I_{CC})	± 50 mA
Storage Temperature (T_{STG})	-65°C to +150°C
Lead Temperature (T_L)	260°C
Soldering (10 seconds)	

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. The data book specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. National does not recommend operation outside databook specifications.

Recommended Operating Conditions

Supply Voltage (V_{CC})	+2.0V to +5.5V
Input Voltage (V_{IN})	0V to +5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	-40°C to +85°C

DC Characteristics for VHC Family Devices

Symbol	Parameter	V _{CC}	74VHC			74VHC		Units	Conditions	
			T _A = 25°C			T _A = -40°C to +85°C				
			Min	Typ	Max	Min	Max			
V _P	Positive Threshold Voltage	3.0			2.20		2.20	V		
		4.5			3.15		3.15			
		5.5			3.85		3.85			
V _N	Negative Threshold Voltage	3.0	0.90			0.90		V		
		4.5	1.35			1.35				
		5.5	1.65			1.65				
V _H	Hysteresis Voltage	3.0	0.30		1.20	0.30	1.20	V		
		4.5	0.40		1.40	0.40	1.40			
		5.5	0.50		1.60	0.50	1.60			
V _{OH}	High Level Output Voltage	2.0	1.9	2.0		1.9		V	V _{IN} = V _{IL}	I _{OH} = -50 μA
		3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V	I _{OH} = -4 mA I _{OH} = -8 mA	
		4.5	3.94			3.80				
V _{OL}	Low Level Output Voltage	2.0		0.0	0.1		0.1	V	V _{IN} = V _{IH}	I _{OL} = 50 μA
		3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V	I _{OL} = 4 mA I _{OL} = 8 mA	
		4.5			0.36		0.44			
I _{IN}	Input Leakage Current	0-5.5			±0.1		±1.0	μA	V _{IN} = 5.5V or GND	
I _{CC}	Quiescent Supply Current	5.5			2.0		20.0	μA	V _{IN} = V _{CC} or GND	

DC Characteristics for 'VHC Family Devices: See Section 2 for Waveforms

Symbol	Parameter	V _{CC}	74VHC		Units	Conditions	Fig. No.
			T _A = 25°C				
			Typ	Limits			
*V _{OLP}	Quiet Output Maximum Dynamic V _{OL}	5.0	0.4	0.8	V	C _L = 50 pF	2-11, 12
*V _{OLV}	Quiet Output Minimum Dynamic V _{OL}	5.0	−0.4	−0.8	V	C _L = 50 pF	2-11, 12
*V _{IHD}	Minimum High Level Dynamic Input Voltage	5.0		3.5	V	C _L = 50 pF	2-11, 12
*V _{ILD}	Maximum Low Level Dynamic Input Voltage	5.0		1.5	V	C _L = 50 pF	2-11, 12

*Parameter guaranteed by design.

AC Electrical Characteristics: See Section 2 for Waveforms

Symbol	Parameter	V _{CC}	74VHC			74VHC		Units	Conditions	Fig. No.
			T _A = 25°C			T _A = -40°C to +85°C				
			Min	Typ	Max	Min	Max			
t _{PLH}	Propagation Delay Time	3.3 ± 0.3		8.3	12.8	1.0	15.0	ns	C _L = 15 pF	2-5
t _{PHL}				10.8	16.3	1.0	18.5		C _L = 50 pF	2-5
		5.0 ± 0.5		5.5	8.6	1.0	10.0	ns	C _L = 15 pF	2-5
				7.0	10.6	1.0	12.0		C _L = 50 pF	2-5
C _{IN}	Input Capacitance			4	10		10	pF	V _{CC} = Open	
C _{PD}	Power Dissipation Capacitance			21				pF	(Note 1)	

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation:

$$I_{CC}(\text{Opr}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6 \text{ (per Gate)}$$